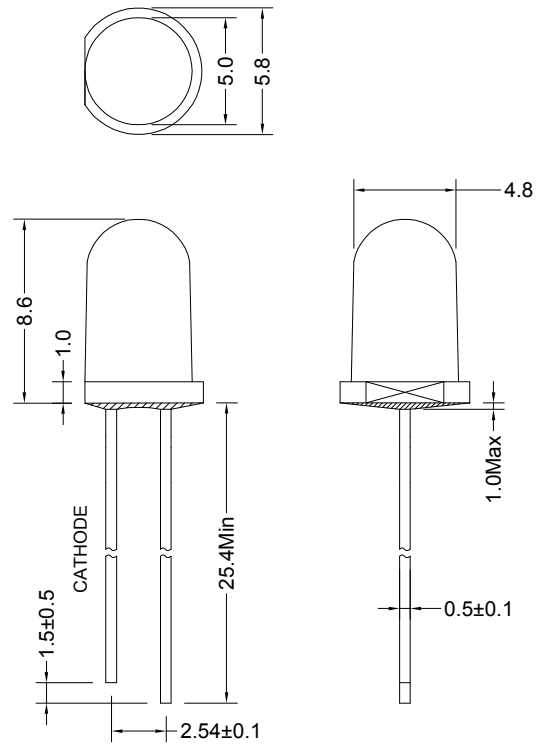


Features:

- Emitting color:Photo Diode
- Lens color:Black
- IC compatible/Low Current capability
- High reliability and long life



Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Test Condition	P		Unit
Reverse Breakdown Voltage	V_{BR}	----	60		V
Power Dissipation	P_d	----	100		mW
Operating Temperature	T_{opr}	----	-40	+85	°C
Storage Temperature	T_{str}	----	-40	+100	°C
Lead Soldering Temperature	T_{sol}	1.60mm from body maximum 3 seconds	260		°C

Electrical and optical characteristics (Ta = 25°C)

Parameter	Symbol	Test Condition	Values			Unit
			Min.	Typ.	Max.	
Light Current	I_L	$V_R=5V$ $H=5\text{mw}/\text{cm}^2$ $\lambda P=940\text{nm}$	----	80	----	μA
Reverse Dark Current	I_D	$V_R=10V$ $H=0\text{mw}/\text{cm}^2$	----	----	30	μA
Short Circuit Current	I_{sc}	$V_R=0V$ $H=5\text{mw}/\text{cm}^2$ $\lambda P=940\text{nm}$	50	----	----	μA
Reverse Breakdown Voltage	V_{BR}	$I_R=100\mu A$ $H=0\text{mw}/\text{cm}^2$	35	----	----	V
Open Circuit Voltage	V_{oc}	$V_R=0V$ $H=5\text{mw}/\text{cm}^2$ $\lambda P=940\text{nm}$	----	0.4	----	V
Peak Sensing Wavelength	λP		----	940	----	nm
Rise Time Fall Time	t_r t_f	$R_L=1K\Omega$ $V_R=10V$	----	45	----	ns
Junction Capacitance	C_T	$V_R=5V$ $H=0\text{mw}/\text{cm}^2$ $f=1.0\text{MHZ}$	----	5	----	PF
Viewing Angle	$2\theta_{1/2}$	$I_F=20\text{mA}$	----	50	----	deg.